# **Enhancement Mode Field Effect Transistor**

#### **N-Channel**

## 2N7002W

#### **Features**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- These Devices are Pb-Free and are RoHS Compliant

#### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	60	V
Drain-Gate Voltage $R_{GS} \le 1.0 \text{ M}\Omega$	$V_{DGR}$	60	V
Gate-Source Voltage  Continuous Pulsed	V <sub>GSS</sub>	±20 ±40	<b>&gt;</b>
Gate-Source Voltage  Continuous  Continuous @ 100°C  Pulsed	I <sub>D</sub>	115 73 800	mA
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Parameter	Symbol	Max	Unit
Total Device Dissipation Derating above T <sub>A</sub> = 25°C	P <sub>D</sub>	200 1.6	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	625	°C/W

<sup>1.</sup> Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch. Minimum land pad size.



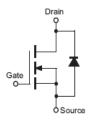
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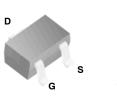


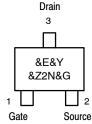
SC-70/SOT-323 CASE 419

#### SIMPLIFIED SCHEMATIC



# MARKING DIAGRAM & PIN ASSIGNMENT





Line 1:

&E = Space

&Y = Binary Year Code

Line 2

&Z = Designates the Assembly Plant Code

2N = Specific Device Code &G = 1-digit Week Code

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
2N7002W	SC-70 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### 2N7002W

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Test Condition		Min	Тур	Max	Units
OFF CHARACTERISTICS (Note 2)	•						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 10 μA		60	78		V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 V$ , $T_C = 25^{\circ}C$			0.001	1.0	μΑ
		<del>  -</del>	T <sub>C</sub> = 125°C		7	500	1
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}, V_{D}$	S = 0 V		0.2	±10	nA
ON CHARACTERISTICS (Note 2)	•						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{GS} = V_{DS}, I_D = 250 \mu A$		1.0	1.76	2.0	V
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	$V_{GS} = 5 \text{ V}, I_D = 0.05 \text{ A}$ $V_{GS} = 10 \text{ V}, I_D = 0.5 \text{ A}, @ T_J = 125 °C$			1.6	7.5	Ω
					2.53	13.5	
On-State Drain Current	I <sub>D(ON)</sub>	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 7.5 V		0.5	1.43		Α
Forward Transconductance	9FS	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.2 A		80	356.5		mS
DYNAMIC CHARACTERISTICS							•
Input Capacitance	C <sub>ISS</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 25 V, f = 1.0 MHz			37.8	50	pF
Output Capacitance	C <sub>OSS</sub>				12.4	25	
Reverse Transfer Capacitance	C <sub>RSS</sub>				6.5	7.0	
SWITCHING CHARACTERISTICS	•	•		•			•
Turn-On Delay Time	t <sub>D(ON)</sub>	$V_{GEN}$ = 10 V, $V_{DD}$ = 30 V, $I_{D}$ = 0.2 A, $R_{L}$ = 150 $\Omega$ , $R_{GEN}$ = 25 $\Omega$			5.85	20	ns
Turn-Off Delay Time	t <sub>D(OFF)</sub>				12.5	20	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Short duration test pulse used to minimize self–heating effect.

#### 2N7002W

#### TYPICAL PERFORMANCE CHARACTERISTICS

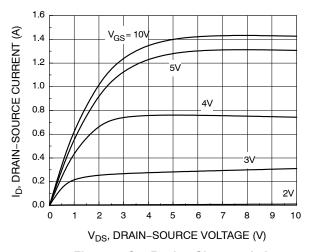


Figure 1. On-Region Characteristics

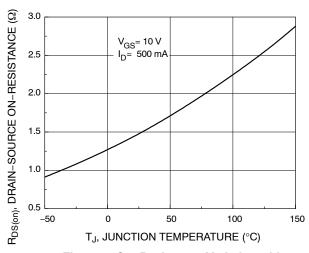


Figure 3. On–Resistance Variation with Temperature

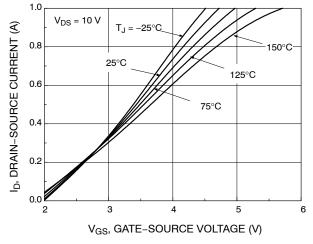


Figure 5. Transfer Characteristics

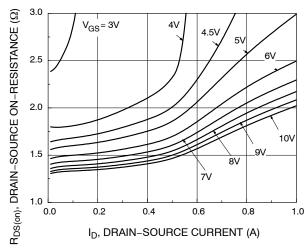


Figure 2. On-Resistance Variation with Gate Voltage and Drain Current

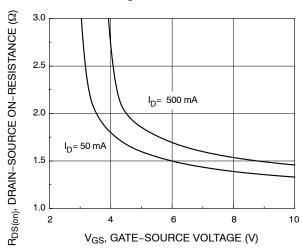


Figure 4. On–Resistance Variation with Gate–Source Voltage

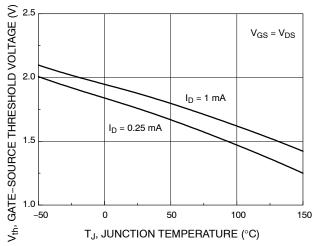


Figure 6. Gate Threshold Variation with Temperature

#### 2N7002W

#### **TYPICAL PERFORMANCE CHARACTERISTICS**

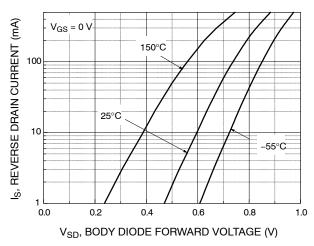


Figure 7. Reverse Drain Current Variation with Diode Forward Voltage and Temperature

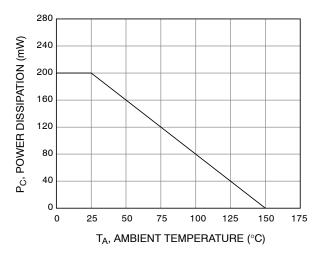
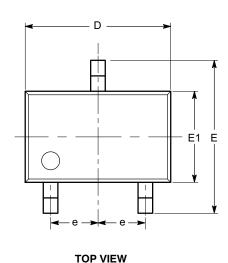


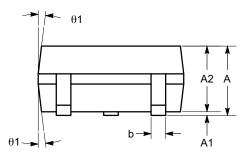
Figure 8. Power Derating

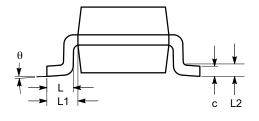
SC-70, 3 Lead, 1.25x2 CASE 419AB-01 ISSUE O

**DATE 19 DEC 2008** 



SYMBOL	MIN	NOM	MAX
Α	0.80		1.10
A1	0.00		0.10
A2	0.80	0.90	1.00
b	0.15		0.30
С	0.08		0.22
D	1.80	2.00	2.20
Е	1.80	2.10	2.40
E1	1.15	1.25	1.35
е	0.65 BSC		
L	0.26	0.36	0.46
L1	0.42 REF		
L2	0.15 BSC		
θ	0°		8°
θ1	4°		10°





**END VIEW** 

# Notes:

- (1) All dimensions are in millimeters. Angles in degrees.(2) Complies with JEDEC MO-203.

**SIDE VIEW** 

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DESCRIPTION:	SC-70, 3 LEAD, 1.25X2		PAGE 1 OF 1	

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